
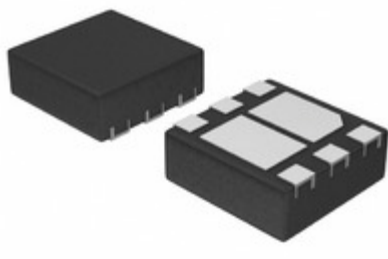
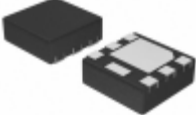
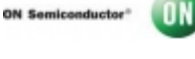
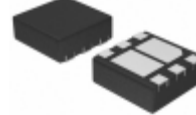
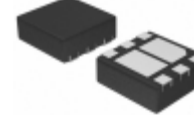
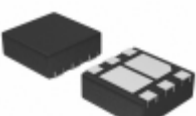
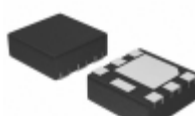
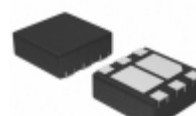
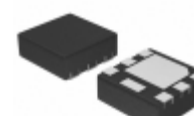
	<h2 style="color: red;">NTLJF4156NT1G</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">NTLJF4156NT1G</a></p> <p><b>Hersteller / Marke:</b> <a href="#">AMI Semiconductor / ON Semiconductor</a></p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 30V 2.5A 6-WDFN</p> <p><b>Datenblätter:</b>  <a href="#">NTLJF4156NT1G.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 8355 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">NTLJF4156NT1G</a>
Hersteller	<a href="#">AMI Semiconductor / ON Semiconductor</a>
Beschreibung	MOSFET N-CH 30V 2.5A 6-WDFN
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	8355 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (Tj)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	6-WDFN Exposed Pad
Supplier Device-Gehäuse	6-WDFN (2x2)
Verlustleistung (max)	710mW (Ta)
Typ FET	N-Channel
FET-Merkmal	Schottky Diode (Isolated)
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	2.5A (Tj)
Rds On (Max) @ Id, Vgs	70 mOhm @ 2A, 4.5V
VGS (th) (Max) @ Id	1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	6.5nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	427pF @ 15V
Antriebsspannung (Max Rds On, Min Rds On)	1.5V, 4.5V
Vgs (Max)	±8V
Verpackung	Tape & Reel (TR)

NTLJF4156NT1G ist neu im Original, Suche NTLJF4156NT1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTLJF4156NT1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTLJF4156NT1G: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>NTLJS1102PTAG</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 8V 3.7A 6-WDFN</p>	 <p><b>NTLJF4156NT</b> AMI Semiconductor / ON Semiconductor NTLJF4156NT ON</p>	 <p><b>NTLJF3117PTAG</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 20V 2.3A 6-WDFN</p>	 <p><b>NTLJF3117PT1G</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 20V 2.3A 6-WDFN</p>
 <p><b>NTLJF3118NTAG</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 20V 2.6A 6-WDFN</p>	 <p><b>NTLJS2103PTAG</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 12V 3.5A 6-WDFN</p>	 <p><b>NTLJF3118NTBG</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 20V 2.6A 6-WDFN</p>	 <p><b>NTLJS1102PTBG</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 8V 3.7A 6-WDFN</p>

### heiße Teile

Mehr

⊛ 04025A3R6BAT2A	↔ 0402ZD473MAT2A	⇒ ADA4862-3YRZ-RL7	D AR8113-AL1E-R	⇒ BZG03C200
⊣ CM150RL-12NFA	⊛ FAN5355UC	D IRFBE20PBF	⇒ IS42S16160D-7BL	⇒ LMV7239M7X/NOPB
⊛ MP1519DQL-LF-Z	⊣ NTLGD3502NT1G	⊛ NTLGD3502NT2G	↔ NTLJ3113PT1G	⇒ NTLJD2105LTBG
D NTLJD3115PT1G	⊛ NTLJD3115PTAG	⊣ NTLJD3119CT1G	⊛ NTLJD3119CTAG	⇒ NTLJD3119CTBG
⇒ NTLJD4116NT1G	↔ NTLJF3117PT1G	⊛ NTLJF4156NTAG	⊣ NTLJS2103P	⇒ NTLJS2103PTAG
↔ NTLJS2103PTBG	⇒ NTLJS3113P	D NTLJS3113PT1G	⊛ NTLJS3113PTAG	⊣ NTLJS3A18PZTWG
⊛ NTLJS4114NT1G	D NTLJS4114NTAG	⇒ NTLLED4901NF	↔ NTLLED4901NFTWG	⇒ NTLTD7900NR2G
⊣ NTLTD7900ZR2	⊛ NTLTD7900ZR2G	↔ NTLUD3A260PZTAG	⇒ NTLUD3A50PZTAG	⇒ NTLUF4189NZTAG
⊛ NTLUS3A18PZTAG	⊣ NTLUS3A40PZTAG	⊛ NTLUS3A40PZTBG	D NTLUS3A90PZTAG	⇒ NTLUS4930NTAG
↔ SMCJ7.5A	⊛ SN75C3223DBR	⊣ SY100EP16VSKC	⊛ TV15C780JB-HF	⇒ UB1111C-TR

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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